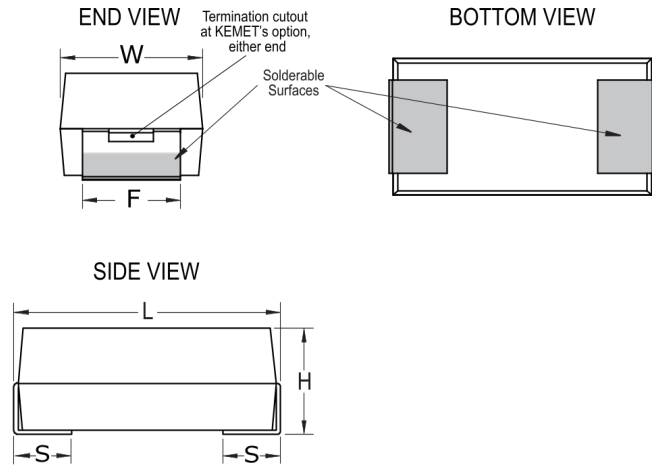


## T493D476K025CB6430

Aliases (DLA Drawing 07016-131KCBC)

T493 HRA, Tantalum, MnO<sub>2</sub> Tantalum, HRA, 47 uF, 10%, 25 VDC, SMD, MnO<sub>2</sub>, Molded, DLA Drawing, C (0.01%/1000 Hrs), 120 mOhms, 7343, Height Max = 3.1mm



Click [here](#) for the 3D model.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information	
Series	T493 HRA
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, MnO <sub>2</sub> , Molded, DLA Drawing
RoHS	Yes
Termination	Gold
AEC-Q200	No
Component Weight	412.33 mg

Specifications	
Capacitance	47 uF
Capacitance Tolerance	10%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	C (0.01%/1000 Hrs)
Resistance	0.12 Ohms (100kHz 25C)
Ripple Current	926 mA (rms, 100kHz 25C)
Leakage Current	11.8 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C And +85C Before Weibull